

## Description

The 74LVC241A provides two 4-bit buffers/drivers with separate output-enable ( $1OE$  and  $2OE$ ) inputs. When  $1OE$  is low or  $2OE$  is high, the device passes noninverted data from the A inputs to the Y outputs. When  $1OE$  is high or  $2OE$  is low, the outputs for the respective buffers/drivers are in the high-impedance state.

The device is designed for operation with a power supply range of 1.65V to 3.6V.

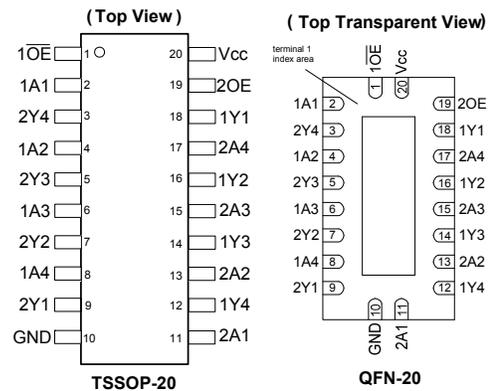
The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output preventing damaging current backflow when the device is powered down.

## Features

- Supply Voltage Range from 1.65V to 3.6V
- Sinks or Sources 24mA at  $V_{CC} = 3V$
- CMOS Low Power Consumption
- $I_{OFF}$  Supports Partial -Power Down Operation
- Inputs or Outputs Accept up to 5.5V
- Inputs Can Be Driven by 3.3V or 5V Allowing for Mixed Voltage Applications
- Schmitt Trigger Action at All Inputs
- Typical  $V_{OLP}$  (Quiet Output Ground Bounce) Less than 0.8V with  $V_{CC} = 3.3V$  and  $T_A = +25^\circ C$
- Typical  $V_{OHV}$  (Quiet Output Dynamic VOH) Greater than 2.0V with  $V_{CC} = 3.3V$  and  $T_A = +25^\circ C$
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115)
  - Exceeds 2000-V Human Body Model (A114)
  - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 250mA per JESD 78, Class I
- All devices are:
  - **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
  - **Halogen and Antimony Free. "Green" Device (Note 3)**

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.  
 2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.  
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

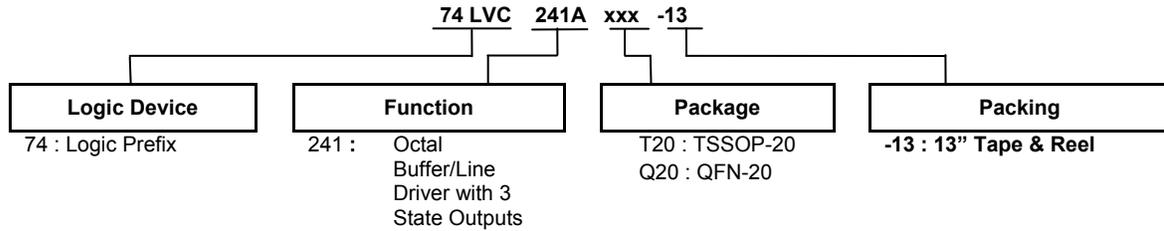
## Pin Assignments



## Applications

- General Purpose Logic
- Bus Driving
- Power Down Signal Isolation
- Wide array of products such as:
  - PCs, Notebooks, Netbooks, Ultrabooks
  - Networking Computer Peripherals, Hard Drives, CD/DVD ROM
  - TV, DVD, DVR, Set Top Box

## Ordering Information



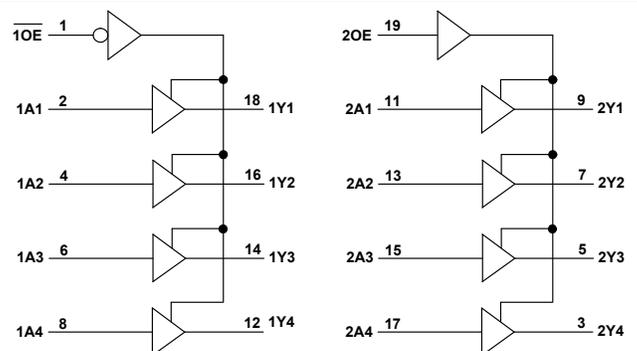
Part Number	Package Code	Package (Note 4 & 5)	Package Size	13" Tape and Reel	
				Quantity	Part Number Suffix
74LVC241AT20-13	T20	TSSOP-20	6.4mm X 6.5mm X 1.2mm 0.65 mm lead pitch	2500/Tape & Reel	-13
74LVC241AQ20-13	Q20	V-QFN4525-20	2.5mm X 4.5mm X 0.95mm 0.50 mm lead pitch	2500/Tape & Reel	-13

- Notes:
4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
  5. V-QFN4525-20 is a JEDEC recognized naming convention that specifies the package thickness category as V and the number 4525 describes the package as 4.5mm X 2.5mm.

## Pin Descriptions

Pin Number	Pin Name	Description
1	$\overline{1OE}$	Output Enable 1
2	1A1	Data Input
3	2Y4	Data Output
4	1A2	Data Input
5	2Y3	Data Output
6	1A3	Data Input
7	2Y2	Data Output
8	1A4	Data Input
9	2Y1	Data Output
10	GND	Ground
11	2A1	Data Input
12	1Y4	Data Output
13	2A2	Data Input
14	1Y3	Data Output
15	2A3	Data Input
16	1Y2	Data Output
17	2A4	Data Input
18	1Y1	Data Output
19	2OE	Output Enable 2
20	Vcc	Supply Voltage

## Logic Diagram



## Function Table

INPUTS		OUTPUTS
$\overline{1OE}$	1An	1Yn
L	L	L
L	H	H
H	X	Z

INPUTS		OUTPUTS
2OE	2An	2Yn
H	L	L
H	H	H
L	X	Z

**Absolute Maximum Ratings** (Notes 6 & 7)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
V <sub>I</sub>	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < 0V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < 0V	-50	mA
I <sub>O</sub>	Continuous Output Current -0.5V < V <sub>O</sub> V <sub>CC</sub> +0.5V	±50	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	100	mA
I <sub>GND</sub>	Continuous Current Through GND	-100	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

- Notes:
- Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
  - Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

**Recommended Operating Conditions** (Note 8)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	Operating	1.65	3.6	V
		Data Retention Only	1.5	—	V
V <sub>I</sub>	Input Voltage	—	0	5.5	V
V <sub>O</sub>	Output Voltage	—	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-Level Output Current	V <sub>CC</sub> = 1.65V	—	-4	mA
		V <sub>CC</sub> = 2.3V	—	-8	
		V <sub>CC</sub> = 2.7V	—	-12	
		V <sub>CC</sub> = 3.0V	—	-24	
I <sub>OL</sub>	Low-Level Output Current	V <sub>CC</sub> = 1.65V	—	4	mA
		V <sub>CC</sub> = 2.3V	—	8	
		V <sub>CC</sub> = 2.7V	—	12	
		V <sub>CC</sub> = 3.0V	—	24	
Δt/ΔV	Input transition Rise or Fall Rate	—	—	10	ns/V
T <sub>A</sub>	Operating Free-Air Temperature	—	-40	+125	°C

- Note: 8. Unused inputs should be held at V<sub>CC</sub> or ground.

**Electrical Characteristics**

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit	
				Min	Max	Min	Max		
V <sub>IH</sub>	High-Level Input Voltage		1.65V to 1.95V	V <sub>CC</sub> X 0.65	—	V <sub>CC</sub> X 0.65	—	V	
			2.3V to 2.7V	1.7	—	1.7	—		
			3.0V to 3.6V	2	—	2	—		
V <sub>IL</sub>	Low-Level input Voltage		1.65V to 1.95V	—	V <sub>CC</sub> X 0.35	—	V <sub>CC</sub> X 0.35	V	
			2.3V to 2.7V	—	0.7	—	0.7		
			3.0V to 3.6V	—	0.8	—	0.8		
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = -50μA	1.65V to 3.6V	V <sub>CC</sub> -0.2	—	V <sub>CC</sub> -0.3	—	V	
		I <sub>OH</sub> = -4mA	1.65V	1.2	—	1.05	—		
		I <sub>OH</sub> = -8mA	2.3V	1.7	—	1.65	—		
		I <sub>OH</sub> = -12mA	2.7V	2.2	—	2.05	—		
			3.0V	2.4	—	2.48	—		
I <sub>OH</sub> = -24mA	3.0V	2.3	—	2.0	—				
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 100μA	1.65V to 3.6V	—	0.2	—	0.3	V	
		I <sub>OL</sub> = 4mA	1.65V	—	0.45	—	0.65		
		I <sub>OL</sub> = 8mA	2.3V	—	0.60	—	0.80		
		I <sub>OL</sub> = 12mA	2.7V	—	0.40	—	0.60		
		I <sub>OL</sub> = 24mA	3.0V	—	0.55	—	0.80		
I <sub>OFF</sub>	Power Down Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 0 or 5.5V	0V	—	±10	—	20	μA	
I <sub>I</sub>	Input Current Control Pins	V <sub>I</sub> = GND or 5.5V	0 to 3.6V	—	±5	—	±20	μA	
I <sub>OZ</sub>	Z-State Current Including Input Current I/O Pins	V <sub>I</sub> = GND or 5.5V V <sub>O</sub> = 0 to 5.5V	3.6V	—	±5	—	±20	μA	
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = GND or V <sub>CC</sub> , I <sub>O</sub> = 0	3.6V	—	10	—	40	μA	
ΔI <sub>CC</sub>	Additional Supply Current	One input at V <sub>CC</sub> -0.6V I <sub>O</sub> = 0A	2.7V to 3.6V	—	500	—	5000	μA	
C <sub>i</sub>	Input Capacitance	Control Pins	V <sub>I</sub> = GND or V <sub>CC</sub>	0V to 3.6V	4.0 typical		4.0 typical		pF
		I/O Pins			5.5 typical		5.5 typical		

**Switching Characteristics**

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t <sub>PD</sub>	Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1	1.8V ± 0.15V	1	6.0	12.2	1	12.7	1	15.1	ns
			2.5V ± 0.2V	1	3.9	7.8	1	8.4	1	9.7	
			2.7V	1	4.2	8.1	1	8.9	1	9.4	
			3.3V ± 0.3V	1.5	3.8	7.6	1.5	8.1	1.5	8.3	
t <sub>EN</sub>	Enable Time OE to Y <sub>N</sub> or OE to Y <sub>N</sub>	Figure 1	1.8V ± 0.15V	1	7	12.8	1	14.8	1	15.5	ns
			2.5V ± 0.2V	1	4.5	9	1	10	1	11.2	
			2.7V	1	5.4	7.5	1	8.1	1	9.0	
			3.3V ± 0.3V	1.5	4.4	6.9	1.5	7.1	1.5	8.7	
t <sub>DIS</sub>	Disable Time OE to Y <sub>N</sub> or OE to Y <sub>N</sub>	Figure 1	1.8V ± 0.15V	1	7	12.8	1	14.8	1	15.5	ns
			2.5V ± 0.2V	1	4.5	9	1	10	1	11.2	
			2.7V	1	5.4	7.5	1	8.1	1	9.0	
			3.3V ± 0.3V	1.7	4.4	6.9	1.7	7.1	1.7	8.7	
t <sub>sk(0)</sub>	Output Skew Time		3.3V ± 0.3V			1.0			1.5	ns	

## Operating Characteristics

T<sub>A</sub> = +25°C

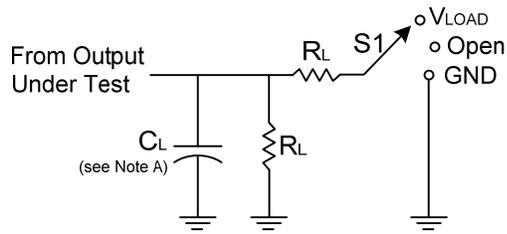
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	TYP	Unit
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	F= 10 MHz Outputs Enabled	1.8V± 0.15V	9.9	pF
			2.5V± 0.2V	10.2	
			3.3V± 0.3V	10.6	

## Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
θ <sub>JA</sub>	Thermal Resistance Junction-to-Ambient	TSSOP-20	(Note 9)	—	74	—	°C/W
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	TSSOP-20	(Note 9)	—	15	—	°C/W
θ <sub>JA</sub>	Thermal Resistance Junction-to-Ambient	V-QFN4525-20	(Note 9)	—	67	—	°C/W
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	V-QFN4525-20	(Note 9)	—	20	—	°C/W

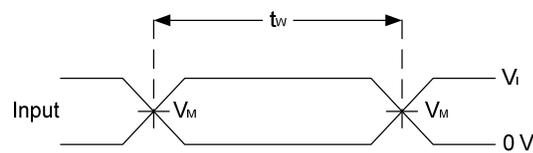
Note: 9. Test conditions for TSSOP-20 and V-QFN4525-20: Devices mounted on 4 layer FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout per JESD 51-7.

**Parameter Measurement Information**

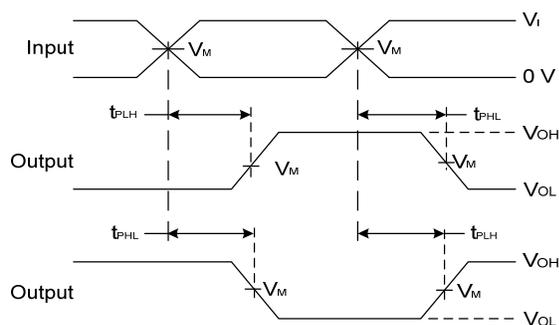


TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	Vload
$t_{PHZ}/t_{PZH}$	GND

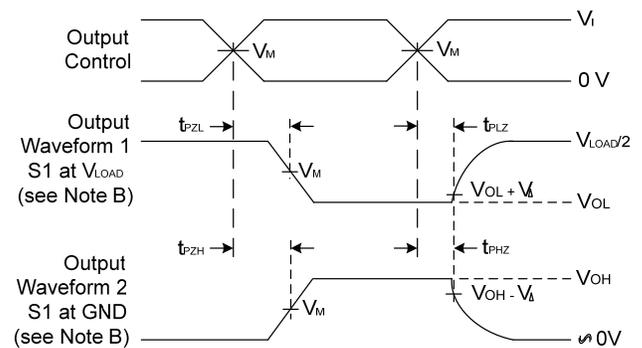
$V_{CC}$	Inputs		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
$1.8V \pm 0.15V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	1K $\Omega$	0.15V
$2.5V \pm 0.2V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	500 $\Omega$	0.15V
2.7V	2.7V	$\leq 2.5ns$	1.5V	6V	50pF	500 $\Omega$	0.3V
$3.3V \pm 0.3V$	2.7V	$\leq 2.5ns$	1.5V	6V	50pF	500 $\Omega$	0.3V



**Voltage Waveform Pulse Duration**



**Voltage Waveform Propagation Delay Times  
Inverting and Non Inverting Outputs**



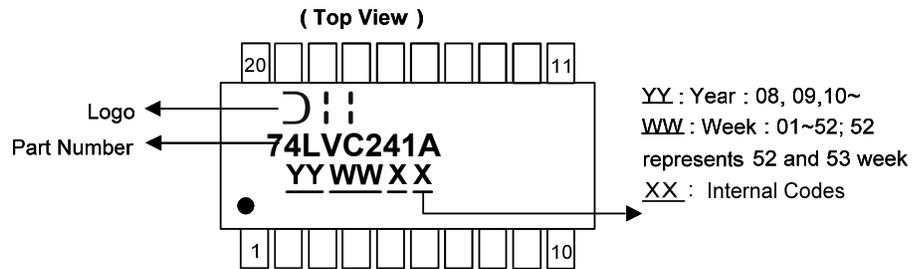
**Voltage Waveform Enable and Disable Times  
Low and High Level Enabling**

- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq 10$  MHz.
  - C. Inputs are measured separately one transition per measurement.
  - D.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - E.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{ENO}$ .
  - F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .

**Figure 1 Load Circuit and Voltage Waveforms**

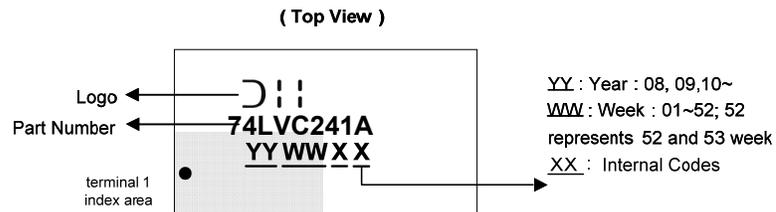
**Marking Information**

(1) TSSOP20



Part Number	Package
74LVC241AT20	TSSOP-20

(2) QFN-20 (V-QFN4525-20)



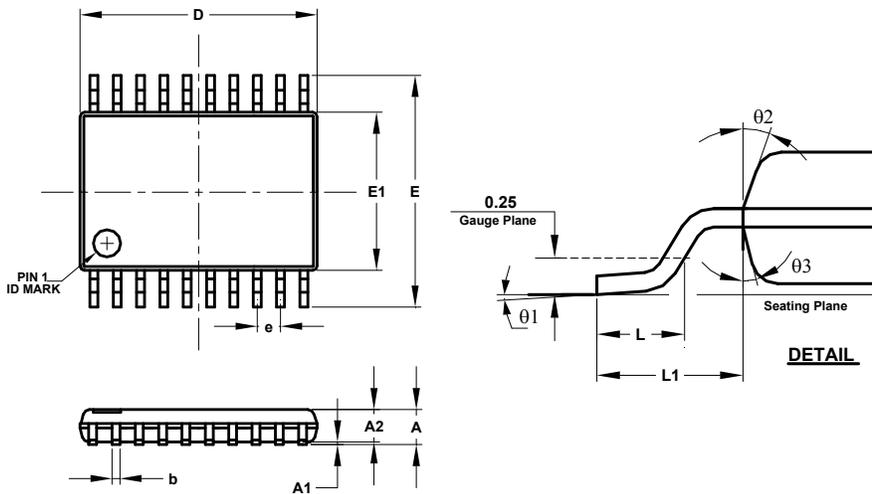
Part Number	Package
74LVC241AQ20	V-QFN4525-20

NEW PRODUCT

**Package Outline Dimensions (All Dimensions in mm)**

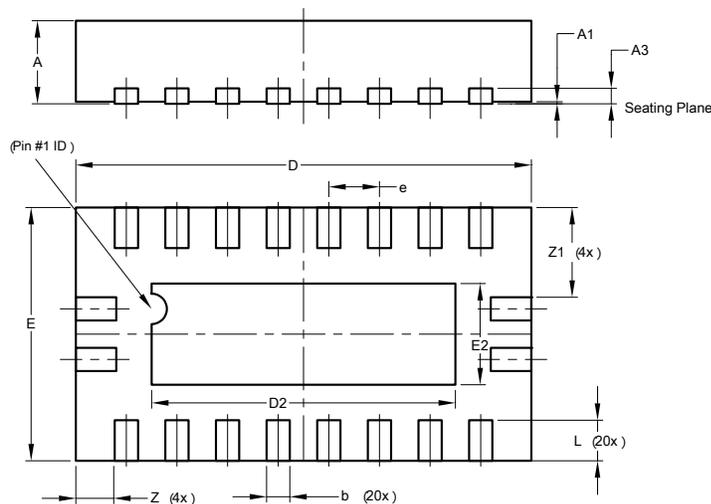
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

**(1) TSSOP-20**



TSSOP-20			
Dim	Min	Max	Typ
A	-	1.20	-
A1	0.05	0.15	-
A2	0.80	1.05	-
b	0.19	0.30	-
c	0.09	0.20	-
D	6.40	6.60	6.50
E	6.20	6.60	6.40
E1	4.30	4.50	4.40
e	0.65 BSC		
L	0.45	0.75	0.60
L1	1.0 REF		
theta1	0°	8°	-
theta2	10°	14°	12°
theta3	10°	14°	12°
All Dimensions in mm			

**(2) QFN-20 (V-QFN4525-20)**



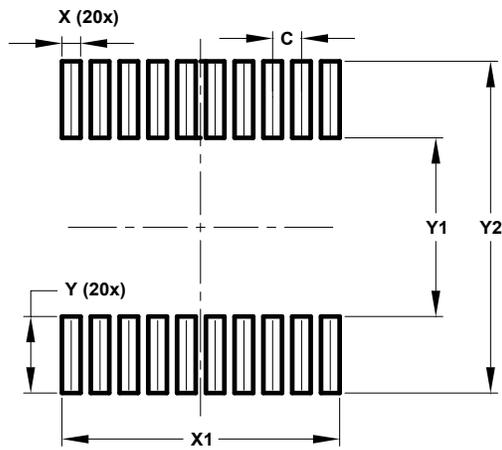
V-QFN4525-20			
Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	0.02
A3	-	-	0.15
b	0.18	0.30	0.23
D	4.45	4.55	4.50
D2	2.85	3.15	3.00
E	2.45	2.55	2.50
E2	0.85	1.15	1.00
e	0.50BSC		
L	0.30	0.50	0.40
Z	-	-	0.385
Z1	-	-	0.885
All Dimensions in mm			

NEW PRODUCT

## Suggested Pad Layout

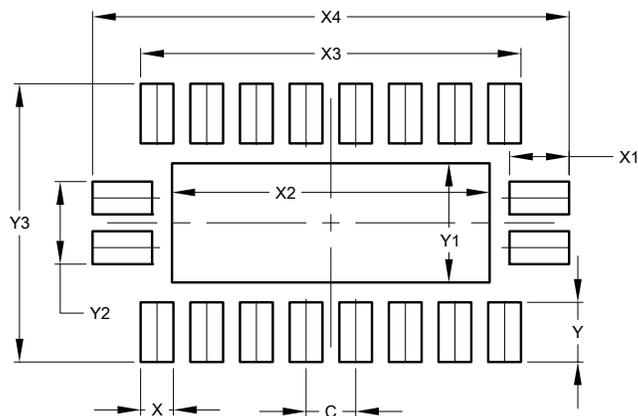
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

### (1) TSSOP-20



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	6.270
Y	1.789
Y1	4.160
Y2	7.720

### (2) QFN-20 (V-QFN4525-20)



Dimensions	Value (in mm)
C	0.500
X	0.330
X1	0.600
X2	3.200
X3	3.830
X4	4.800
Y	0.600
Y1	1.200
Y2	0.830
Y3	2.800

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